

# TRIAC ( ISOLATED MOLD TYPE )

## TG16C

UL:E76102(M)

**SanRex** Triac TG16C is isolated mold TRIAC suitable for wide range of applications like Copier Machines, Micro Wave Ovens, Solid State Switches, Motor Controls, Light Controls and Heater Controls.

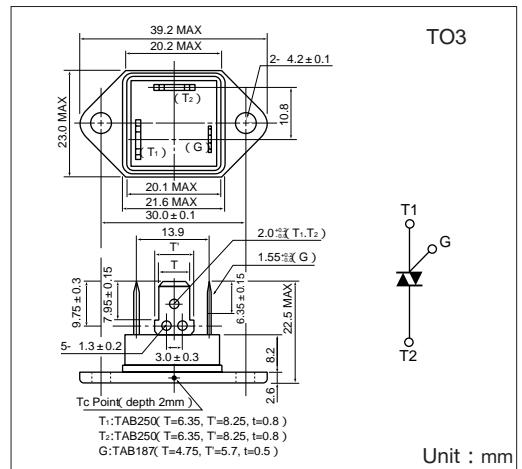
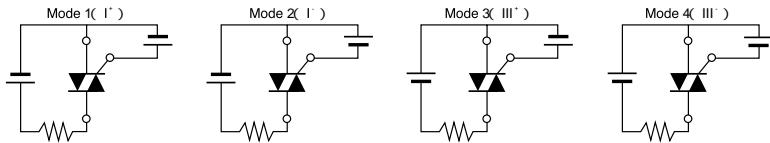
$I_{T(AV)}$  16A

High surge capability 160A

Isolated Mounting AC2500V

Tab Terminals

Trigger mode of the triac



### Maximum Ratings

(  $T_j = 25$  unless otherwise specified )

Symbol	Item	Ratings		Unit
		TG16C40	TG16C60	
$V_{DRM}$	Repetitive Peak Off-State Voltage	400	600	V
$I_{T(RMS)}$	R.M.S. On-State Current	16	A	
$I_{TSM}$	Surge On-State Current	140/160	A	
$I^t$	$I^t$	106	A°S	
$P_{GM}$	Peak Gate Power Dissipation	10	W	
$P_{G(AV)}$	Average Gate Power Dissipation	1	W	
$I_{GM}$	Peak Gate Current	3	A	
$V_{GM}$	Peak Gate Voltage	10	V	
$di/dt$	Critical Rate of Rise of On-State Current	$I_G = 100\text{mA}, T_j = 25, V_D = \frac{1}{2}V_{DRM}, \frac{dI}{dt} = 1\text{A}/\mu\text{s}$	50	$\text{A}/\mu\text{s}$
$T_j$	Operating Junction Temperature	- 25 to + 125		
$T_{stg}$	Storage Temperature	- 40 to + 125		
$V_{iso}$	Isolation Breakdown Voltage ( R.M.S. )	2500	V	
	Mounting Torque( M4 )	1.5 ( 15 )	$\text{N}\cdot\text{m}$ ( $\text{kgf}\cdot\text{cm}$ )	
	Mass	23	g	

### Electrical Characteristics

Symbol	Item	Conditions	Ratings	Unit
$I_{DRM}$	Repetitive Peak Off-State Current, max	$V_D = V_{DRM}$ , Single phase, half wave, $T_j = 125$	3	mA
$V_{TM}$	Peak On-State Voltage, max	On-State Current [ $2 \times I_{T(RMS)}$ ], Inst. measurement	1.5	V
$I_{GT1}^+$	Gate Trigger Current, max	$T_j = 25, I_T = 1\text{A}, V_D = 6\text{V}$	50	mA
$I_{GT1}^-$		$T_j = 25, I_T = 1\text{A}, V_D = 6\text{V}$	50	
$I_{GT3}^+$		-	-	
$I_{GT3}^-$		$T_j = 25, I_T = 1\text{A}, V_D = 6\text{V}$	50	
$V_{GT1}^+$	Gate Trigger Voltage, max	$T_j = 25, I_T = 1\text{A}, V_D = 6\text{V}$	3	V
$V_{GT1}^-$		$T_j = 25, I_T = 1\text{A}, V_D = 6\text{V}$	3	
$V_{GT3}^+$		-	-	
$V_{GT3}^-$		$T_j = 25, I_T = 1\text{A}, V_D = 6\text{V}$	3	
$V_{GD}$	Non-Trigger Gate Voltage, min	$T_j = 125, V_D = \frac{1}{2}V_{DRM}$	0.2	V
$tgt$	Turn On Time, max.	$I_{T(RMS)}, I_G = 100\text{mA}, V_D = \frac{1}{2}V_{DRM}, T_j = 25, \frac{dI}{dt} = 1\text{A}/\mu\text{s}$	10	V
$dv/dt$	Critical Rate of Rise on-State Voltage,min.	$T_j = 125, V_D = \frac{2}{3}V_{DRM}$ , Exponential wave.	50	$\text{V}/\mu\text{s}$
$(dv/dt)_c$	Critical Rate of Rise off-State Voltage at commutation, min	$T_j = 125, V_D = \frac{2}{3}V_{DRM}, (dv/dt)_c = 8\text{A}/\text{ms}$	6	$\text{V}/\mu\text{s}$
$I_H$	Holding Current, typ.	$T_j = 25$	30	mA
$R_{th(j-c)}$	Thermal Impedance, max	Junction to case	2.0	/W

